

FORM PTO-1449 (References cited in prior art application serial no. <u>09/724,820</u>) Page 13 of 13	Atty. Docket No.: H26341 D2 (1139.1124104)	Serial No.: 10/617,892
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	Applicant: Ralph H. Johnson et al.	
	Filing Date: July 11, 2003	Group Art: unknown

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EXAMINER: <i>[Signature]</i>	DATE CONSIDERED: 8/19/05
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.